SCES682C - DECEMBER 2008-REVISED FEBRUARY 2009

SDIO PORT EXPANDER WITH VOLTAGE-LEVEL TRANSLATION

FEATURES

- 6-to-12 Demultiplexer/Multiplexer Allows SDIO **Port Expansion**
- **Built-in Level Translator Eliminates Voltage** Mismatch Between Baseband and SD Card or **SDIO Peripheral**
- V_{CCA}, V_{CCB0}, and V_{CCB1} Each Operate Over Full 1.1-V to 3.6-V Range
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Performance A Port**
 - 2000-V Human-Body Model (A114-B)
 - 100-V Machine Model (A115-A)
 - 1500-V Charged-Device Model (C101)
- ±8-kV Contact Discharge IEC 61000-4-2 ESD Performance (B Port)

DESCRIPTION/ORDERING INFORMATION

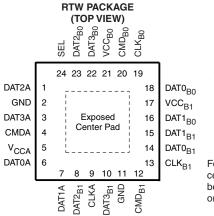
The TXS02612 is designed to interface the cell phone baseband with external SDIO peripherals. The device includes a 6-channel SPDT switch with voltage-level translation capability. This allows a single SDIO port to be interfaced with two SDIO peripherals. The TXS02612 has three separate supply rails that operate over the full range of 1.1 V to 3.6 V. This allows the baseband and SDIO peripherals to operate at different supply voltages if required.

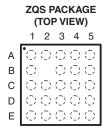
The select (SEL) input is used to choose between the B0 port and B1 port. When SEL = Low, B0 port is selected; when SEL = High, B1 port is selected. SEL is referenced to V_{CCA}. For the unselected B port, the clock output is held low, whereas the data and command I/Os are pulled high to their respective V_{CCB} through a 70-k Ω resistor (±30% tolerance).

ORDERING INFORMATION(1)

T _A	PACKAGE	(2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
-40°C to 85°C	MicroStar Junior™ BGA (VFBGA) – ZQS	Reel of 3000	TXS02612ZQSR	YJ612		
	QFN – RTW	Reel of 3000	TXS02612RTWR	YJ612		

- For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.





For RTW, if the exposed center pad is used, it must be connected to ground or electrically open.

Table 1. ZQS PACKAGE TERMINAL ASSIGNMENTS

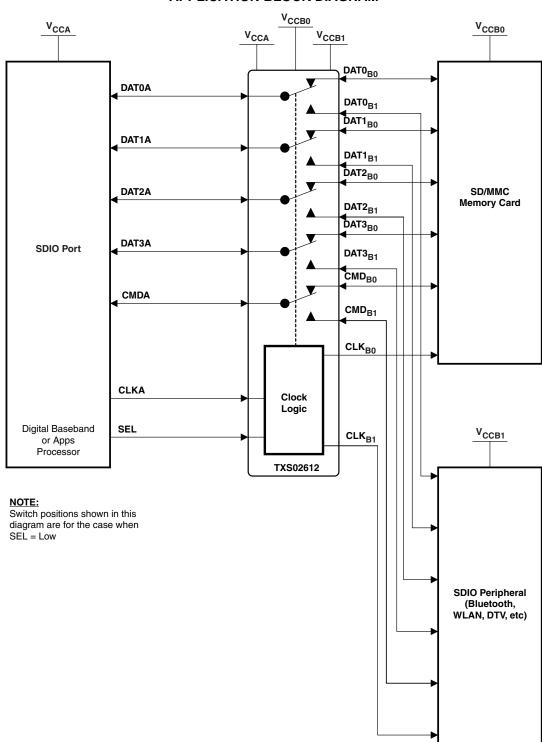
	1	2	3	4	5
Α	DAT2A	SEL	DAT3 _{B0}	CMD _{B0}	CLK _{B0}
В	DAT3A		DAT2 _{B0}	V _{CCB0}	DAT0 _{B0}
С	CMDA	V_{CCA}	GND	V _{CC B1}	DAT1 _{B0}
D	DAT0A	CLKA	GND	DAT1 _{B1}	DAT0 _{B1}
E	DAT1A	DAT2 _{B1}	DAT3 _{B1}	CMD _{B1}	CLK _{B1}



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



APPLICATION BLOCK DIAGRAM

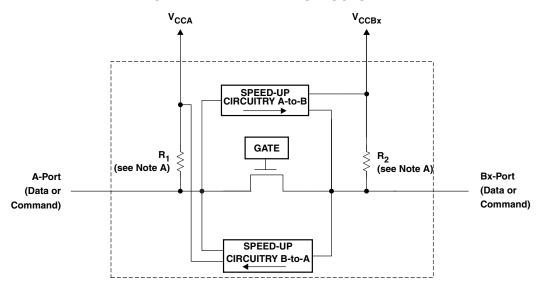


PIN ASSIGNMENTS

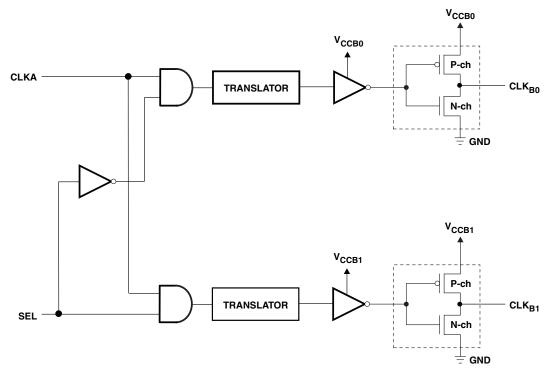
			FIN ASSIGNMENTS	
RTW PACKAGE PIN NO.	ZQS PACKAGE BALL NO.	NAME	FUNCTION	TYPE
1	A1	DAT2A	Data bit 2. Referenced to V _{CCA} .	I/O
3	B1	DAT3A	Data bit 3. Referenced to V _{CCA} .	I/O
4	C1	CMDA	Command bit. Referenced to V _{CCA} .	I/O
6	D1	DAT0A	Data bit 0. Referenced to V _{CCA} .	I/O
7	E1	DAT1A	Data bit 1. Referenced to V _{CCA} .	I/O
24	A2	SEL	Select pin to choose between B0 and B1. Referenced to V _{CCA} .	Input
	B2		Depopulated	
5	C2	V _{CCA}	A-port supply voltage. 1.1 V \leq V _{CCA} \leq 3.6 V.	Power
9	D2	CLKA	Clock input A. Referenced to V _{CCA} .	Input
8	E2	DAT2 _{B1}	Data bit 2. Referenced to V _{CCB1} .	I/O
22	А3	DAT3 _{B0}	Data bit 3. Referenced to V _{CCB0} .	I/O
23	B3	DAT2 _{B0}	Data bit 2. Referenced to V _{CCB0} .	I/O
2	C3	GND	Ground	
11	D3	GND	Ground	
10	E3	DAT3 _{B1}	Data bit 3. Referenced to V _{CCB1} .	I/O
20	A4	CMD _{B0}	Command bit. Referenced to V _{CCB0} .	I/O
21	B4	V_{CCB0}	B0-port supply voltage. 1.1 V \leq V _{CCB0} \leq 3.6 V.	Power
17	C4	V _{CCB1}	B1-port supply voltage. 1.1 V \leq V _{CCB1} \leq 3.6 V.	Power
15	D4	DAT1 _{B1}	Data bit 1. Referenced to V _{CCB1} .	I/O
12	E4	CMD _{B1}	Command bit. Referenced to V _{CCB1} .	I/O
19	A5	CLK _{B0}	Clock output. Referenced to V _{CCB0} .	Output
18	B5	DAT0 _{B0}	Data bit 0. Referenced to V _{CCB0} .	I/O
16	C5	DAT1 _{B0}	Data bit 1. Referenced to V _{CCB0} .	I/O
14	D5	DAT0 _{B1}	Data bit 0. Referenced to V _{CCB1} .	I/O
13	E5	CLK _{B1}	Clock output. Referenced to V _{CCB1} .	Output



SIMPLIFIED INTERNAL STRUCTURE



Simplified Architecture of Command and Each Data Path



Simplified Architecture of the Clock Path

- A. R₁ and R₂ resistor values are determined based upon the logic level applied to the A port or B port, as follows:
 - R_1 and R_2 = 40 $k\Omega$ when a logic level low is applied to the A port or B port.
 - R_1 and R_2 = 4 $k\Omega$ when a logic level high is applied to the A port or B port.
 - R_1 and R_2 = 70 k Ω when the port is deselected.

FUNCTION TABLE

		Clock Channel	
SEL	CLKB0	CLKB1	OPERATION
L	Active	Low	CLKA to CLKB0
Н	Low	Active	CLKA to CLKB1
	Da	ata and Command Channel	
SEL	DATxB0 or CMDxB0	DATxB1 or CMDxB1	OPERATION
L	Active	Disabled, pulled to V_{CCB1} through 70 k Ω	DATxA to DATxB0, CMDA to CMDB0
Н	Disabled, pulled to V_{CCB0} through 70 k Ω	Active	DATxA to DATxB1, CMDA to CMDB1

ABSOLUTE MAXIMUM RATINGS(1) (2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA} V _{CCB0} V _{CCB1}	Supply voltage range ⁽²⁾		-0.5	4.6	V
VI	Input voltage range	A port, B0 port, B1 port, control inputs	-0.5	V _{CCx} + 0.5	V
Vo	Voltage range applied to any output in the high-impedance or power-off state	A port, B0 port, B1 port	-0.5	V _{CCx} + 0.5	V
I_{lK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		- 50	mA
I _{CC} / I _{GND}	Continuous current through V_{CCA} , V_{CCB0} , V_{CCB1} , or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

PACKAGE THERMAL IMPEDANCE

	PARAMET		UNIT	
θ_{JA}	Dealers thermal impedance	RTW package	66	°C/M
	Package thermal impedance	ZQS package	171.6	°C/W

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.



RECOMMENDED OPERATING CONDITIONS

			V _{CCA}	V _{CCBx} ⁽¹⁾	MIN	MAX	UNIT
V _{CCA} V _{CCB0} V _{CCB1}	Supply voltage				1.1	3.6	V
		A-port I/Os			V _{CCI} - 0.2	V_{CCI}	
V_{IH}	High-level input voltage	B-port I/Os	1.1 V to 3.6 V	1.1 V to 3.6 V	V _{CCI} - 0.2	V _{CCI}	V
		SEL, CLKA			$V_{CCA} \times 0.65 V$	3.6	
		A-port I/Os			0	0.15	
V_{IL}	Low-level input voltage	B-port I/Os	1.1 V to 3.6 V	1.1 V to 3.6 V	0	0.15	V
		SEL, CLKA			0	$V_{CCA} \times 0.35$	
Δt/Δν	Input transition rise or fall rate	CLK, SEL				10	ns/V
T _A	Operating free-air temperature				-40	85	°C

⁽¹⁾ V_{CCBx} refers to V_{CCB0} and V_{CCB1} .

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER	TEST CONDITIONS	V	V	$T_A = 25^{\circ}C$	$T_A = -40^{\circ}C$ to	85°C	UNIT
PARAMETER	TEST CONDITIONS	V _{CCA}	V _{CCBx}	TYP	MIN	MAX	UNII
		1.1 V	1.1 V		0.74		
V_{OHA}		1.4 V	1.4 V		V _{CCA} × 0.67		
(DATA &	$I_{OH} = -20 \mu A,$ $V_{IBx} \ge V_{CCBx} - 0.2 V$	1.65 V	1.65 V		V _{CCA} × 0.67		V
CMD)	VIBX = VCCBX U.2 V	2.3 V	2.3 V		V _{CCA} × 0.67		
		3 V	3 V		V _{CCA} × 0.67		
	$I_{OL} = 135 \mu A, V_{IBx} \le 0.15 V$	1.1 V	1.1 V			0.35	
V_{OLA}	$I_{OL} = 180 \mu A, V_{IBx} \le 0.15 V$	1.4 V	1.4 V			0.35	
(DATA &	I _{OL} = 220 μA, V _{IBx} ≤ 0.15 V	1.65 V	1.65 V			0.45	V
CMD)	I _{OL} = 300 μA, V _{IBx} ≤ 0.15 V	2.3 V	2.3 V			0.55	
	$I_{OL} = 620 \mu A, V_{IBx} \le 0.15 V$	3 V	3 V			0.70	
		1.1 V	1.1 V		0.74		
V_{OHB}		1.4 V	1.4 V		V _{CCBx} × 0.67		
(DATA & CMD)	$\begin{split} I_{OH} &= -20 \ \mu\text{A}, \\ V_{IAx} &\geq V_{CCAx} - 0.2 \ V \end{split}$	1.65 V	1.65 V		$V_{CCBx} \times 0.67$		V
		2.3 V	2.3 V		$V_{CCBx} \times 0.67$		
		3 V 3 V V _{CCBx} × 0.67					
	$I_{OH} = -0.5 \text{ mA}$	1.1 V	1.1 V		0.74		
	I _{OH} = - 1 mA	1.4 V	1.4 V		1.05		
V _{OHCLKB}	I _{OH} = -2 mA	1.65 V	1.65 V		1.2		V
	I _{OH} = - 4 mA	2.3 V	2.3 V		1.75		
	$I_{OH} = -8 \text{ mA}$	3 V	3 V		2.3		
	$I_{OL} = 135 \mu A, V_{IAx} \le 0.15 V$	1.1 V	1.1 V			0.35	
V_{OLB}	I _{OL} = 180 μA, V _{IAx} ≤ 0.15 V	1.4 V	1.4 V			0.35	
(DATA &	I _{OL} = 220 μA, V _{IAx} ≤ 0.15 V	1.65 V	1.65 V			0.45	V
CMD)	$I_{OL} = 300 \mu A, V_{IAX} \le 0.15 V$	2.3 V	2.3 V			0.55	
	$I_{OL} = 620 \mu A, V_{IAX} \le 0.15 V$	3 V	3 V			0.70	
	I _{OL} = 0.5 mA	1.1 V	1.1 V			0.35	
	I _{OL} = 1 mA	1.4 V	1.4 V			0.35	
/ _{OLCLKB}	I _{OL} = 2 mA	1.65 V	1.65 V			0.45	V
	I _{OL} = 4 mA	2.3 V	2.3 V			0.55	
	I _{OL} = 8 mA	3 V	3 V			0.7	

ELECTRICAL CHARACTERISTICS (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	V	T _A = 25°C	$T_A = -40$ °C to 85°C	UNIT	
PARAMETER	TEST CONDITIONS	V _{CCA} V _{CCBx}		TYP	MIN MAX	UNIT	
1	SEL, CLKA	1.1 V to 3.6 V	1.1 V to 3.6 V	±1	±2	^	
Ч	DAT, CMD	1.1 V 10 3.6 V	1.1 V 10 3.6 V	±1	±2	μА	
		1.1 V to 3.6 V	1.1 V to 3.6 V		12		
I _{CCA}	$V_1 = V_0 = \text{Open}, I_0 = 0,$ SEL, CLK = High or Low	3.6 V	0 V		12	μА	
		0 V	3.6 V		-1		
	_	1.1 V to 3.6 V	1.1 V to 3.6 V		24		
I _{CCB0} or I _{CCB1}	$V_I = V_O = Open, I_O = 0,$ SEL, CLK = High or Low	3.6 V	0 V		-12	μА	
ICCB1	CLE, CLIK - Flight of Low	0 V	3.6 V		24		
C _i	SEL, CLKA	3.3 V	3.3 V	2.5	3.5	pF	
<u> </u>	A port	3.3 V	221/	7	7.5	~F	
C _{io}	B port	3.3 V	3.3 V	9.5	10	pF	

TIMING REQUIREMENTS

 $T_A = 25^{\circ}C, V_{CCA} = 1.2 \text{ V}$

				V _{CCB} = 1.2 V	V _{CCB} = 1.5 V	V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	UNIT
				TYP	TYP	TYP	TYP	TYP	UNIT
Data rate	Command	Push-pull driving		60	80	120	120	120	Maria
		Open-drain driving		2	2	2	2	2	Mbps
	Clock	Push-pull driving		30	40	60	60	60	MHz
	Data	Push-pull driving		60	80	120	120	120	Mbps
	Pulse duration	Push-pull driving	CLK	17	13	8	8	8	
t _w		Open-drain driving	CMD	500	500	500	500	500	ns
		Push-pull	Data	17	13	8	8	8	
		driving	CMD	17	13	8	8	8	



TIMING REQUIREMENTS

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

				V _{CCB} = 1.2 V		V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		2.5 V 2 V	V _{CCB} = 3.3 V ± 0.3 V		UNIT
				TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data	Command	Push-pull dri	ving	60		80		120		120		120	Mhaa
	Command	Open-drain driving		2		2		2		2		2	Mbps
	Clock	Push-pull driving		30		40		60		60		60	MHz
	Data	Push-pull driving		60		80		120		120		120	Mbps
		Push-pull driving	CLK	17	13		8		8		8		
t _w	Pulse duration	Open-drain driving	CMD	500	500		500		500		500		ns
		Push-pull	Data	17	13		8		8		8		
		driving	CMD	17	13		8		8		8		

TIMING REQUIREMENTS

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (unless otherwise noted)

				V _{CCB} = 1.2 V	V V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
				TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	C	Push-pull dri	ving	60		80		120		120		120	Mana
Data	Command	Open-drain driving		2		2		2		2		2	Mbps
	Clock	Push-pull driving		30		40		60		60		60	MHz
	Data	Push-pull driving		60		80		120		120		120	Mbps
		Push-pull driving	CLK	17	13		8		8		8		
t _w	Pulse duration	Open-drain driving	CMD	500	500		500		500		500		ns
		Push-pull	Data	17	13		8		8		8		
		driving	CMD	17	13		8		8		8		

TIMING REQUIREMENTS

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

				V _{CCB} = 1.2 V	V _{CCB} = ± 0.7		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		UNIT
				TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	Command	Push-pull dri	ving	60		80		120		120		120	Mhna
Data	Command	Open-drain o	driving	2		2		2		2		2	Mbps
rate	Clock	Push-pull dri	ving	30		40		60		60		60	MHz
	Data	Push-pull dri	ving	60		80		120		120		120	Mbps
		Push-pull driving	CLK	17	13		8		8		8		
t _w	Pulse duration	Open-drain driving	CMD	500	500		500		500		500		ns
		Push-pull	Data	17	13		8		8		8		
		driving	CMD	17	13		8		8		8		

TIMING REQUIREMENTS

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted)

				V _{CCB} = 1.2 V	V _{CCB} = ± 0.7		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2				UNIT		
				TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX			
	Command	Push-pull dri	ving	60		80		120		120		120	Mhna		
Data	Command	Open-drain o	driving	2		2		2		2		2	Mbps		
rate	Clock	Push-pull dri	ving	30		40		60		60		60	MHz		
	Data	Push-pull dri	ving	60		80		120		120		120	Mbps		
		Push-pull driving	CLK	17	13		8		8		8				
t _w	Pulse duration	Open-drain driving	CMD	500	500		500		500		500		ns		
	duration		duration	Push-pull	Data	17	13		8		8		8		
		driving	CMD	17	13		8		8		8				



SWITCHING CHARACTERISTICS

 $T_A = 25$ °C, $V_{CCA} = 1.2 \text{ V}$

DADAMETED	FROM	то	TEST	V _{CCB} = 1.2 V	V _{CCB} = 1.5 V	V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	LINUT
PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	TYP	TYP	TYP	TYP	TYP	UNIT
	CMDA	CMDD	Push-pull driving	5.9	4.8	4.4	4	4.46	
	CMDA	CMDB	Open-drain driving	238	214	192	159	140	
	CMDD	CMDA	Push-pull driving	5.6	4.8	4.4	4.1	4	
	CMDB	CMDA	Open-drain driving	227	201	176	137	114	
t _{PD}	CLKA	CLKB	Push-pull driving	5.5	4.1	3.6	3.2	3	ns
	DATA	DATB	D 1 11	5.8	4.8	4.4	4.2	6.8	
	DATB	DATA	Push-pull driving	5.6	4.8	4.4	4.1	4	
	SEL	B-Port	Push-pull driving	13	11	10	9.4	9.1	
t _{rA}	A-port	rise time	Push-pull driving	4.8	5.1	5.1	5.3	5.7	
t _{rB}	B-port	rise time	Push-pull driving	6.1	3.8	2.9	1.9	1.5	
t _{rB}	CLKA	CLKB	Push-pull driving	5.2	3.4	2.6	1.7	1.3	
t _{fA}	A-port	fall time	Push-pull driving	3.4	2.8	2.6	2.6	2.6	ns
t _{fB}	B-port	fall time	Push-pull driving	4.2	3	2.3	1.7	1.5	
t _{fB}	CLKA	CLKB	Push-pull driving	3.1	2.1	1.6	1.2	1	
	ChA-to-	ChB skew	Push-pull driving	0.4	0.4	0.3	0.4	0.4	
t	ChB-to-	ChA skew	Push-pull driving	0.3	0.3	0.3	0.3	0.4	ns
t _{sk(O)}		el-to-Clock kew	Push-pull driving	1.68	1.5	1.5	1.5	1.7	113
	_		Push-pull driving	60	80	120	120	120	
	Con	nmand	Open-drain driving	2	2	2	2	2	Mbps
Max data rate	С	lock	Push-pull driving	30	40	60	60	60	MHz
	С	Data	Push-pull driving	60	80	120	120	120	Mbps

SWITCHING CHARACTERISTICS

over operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = 1 ± 0.15	1.8 V 5 V	V _{CCB} = ± 0.2		V _{CCB} = ± 0.3	3.3 V 3 V	UNIT
	(INPUT)	(OUTPUT)	CONDITIONS	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	CMDA	CMDB	Push-pull driving	5.1		13		9		8		7.5	
	CIVIDA	CIVIDB	Open-drain driving	210		777		756		684		758	
	CMDB	CMDA	Push-pull driving	4.5		10.6		9.2		8.5		8.2	
	CIVIDB	CIVIDA	Open-drain driving	200		616		560		433		375	ns
t _{PD}	CLKA	CLKB	Push-pull driving	4.7		13.1		9.8		6		5.2	115
	DATA	DATB	Push-pull driving	5.1		13		9		8		7.8	
	DATB	DATA	Push-pull driving	4.5		11		9.3		8.8		8.4	
	SEL	B-Port	Push-pull driving	9.5		26		21		19		18	
t _{rA}	A-port	rise time	Push-pull driving	2.7	1.5	5.8	1.7	5.9	1.7	6	1.8	6.1	
t _{rB}	B-port	rise time	Push-pull driving	3.3	1.7	8.2	1.3	6.6	1	4.3	8.0	2.9	ns
t _{rB}	CLKA	CLKB	Push-pull driving	5.2	1.7	6.4	1.3	4.9	0.9	3.2	8.0	2.5	
t _{fA}	A-port	fall time	Push-pull driving	2.4	1	3.9	0.9	3.4	0.9	3.2	1.3	3.3	
t _{fB}	B-port	fall time	Push-pull driving	3.7	1.1	6.3	0.9	5.2	0.6	3.9	0.6	3.2	ns
t _{fB}	CLKA	CLKB	Push-pull driving	3.1	0.9	4.1	0.8	3.2	0.5	2.2	0.5	1.9	
	ChA-to-	ChB skew	Push-pull driving	0.32		0.47		0.58		0.63		0.63	
turo	ChB-to-	ChA skew	Push-pull driving	0.27		0.24		0.23		0.22		0.22	ns
t _{sk(O)}		el-to-Clock kew	Push-pull driving	1.47		1.66		1.68		1.82		1.77	110
	0		Push-pull driving	60		80		120		120		120	Misses
May data rat-	Con	nmand	Open-drain driving	2		2		2		2		2	Mbps
Max data rate	С	lock	Push-pull driving	30		40		60		60		60	MHz
	D	ata	Push-pull driving	60		80		120		120		120	Mbps



SWITCHING CHARACTERISTICS

over operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = ± 0.15		V _{CCB} = ± 0.2		V _{CCB} = 1.		UNIT
	(INFUI)	(OUTPUT)	CONDITIONS	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	CMDA	CMDB	Push-pull driving	4.8		12		8		6		5.7	
	CIVIDA	CIVIDB	Open-drain driving	183		726		715		686		780	
	CMDB	CMDA	Push-pull driving	4		9		7		6.4		6	
	CIVIDE	CIVIDA	Open-drain driving	175		565		563		441		392	ns
t _{PD}	CLKA	CLKB	Push-pull driving	4.5		13		9		5.4		4.5	115
	DATA	DATB	Push-pull driving	4.7		12		8.4		6		5.8	
	DATB	DATA	Push-pull driving	4.1		9		7.5		6.4		6.3	
	SEL	B-Port	Push-pull driving	8.2		22		17		14.8		14	
t _{rA}	A-port	rise time	Push-pull driving	2	1.1	4	1.1	4.3	1.2	4.5	1.3	4.6	
t _{rB}	B-port	rise time	Push-pull driving	6.2	1.7	7.9	1.2	6.2	1	4.3	0.8	3.1	ns
t _{rB}	CLKA	CLKB	Push-pull driving	5.2	1.7	6.4	1.3	4.9	0.9	3.2	0.8	2.5	
t _{fA}	A-port	fall time	Push-pull driving	1.8	0.8	3.2	0.7	2.8	0.7	1.7	0.7	2.6	
t _{fB}	B-port	fall time	Push-pull driving	3.5	1	5.6	0.9	3.5	0.6	1.9	0.6	3	ns
t _{fB}	CLKA	CLKB	Push-pull driving	3.1	0.9	4.1	0.8	3.2	0.5	2.2	0.5	1.9	
	ChA-to-	ChB skew	Push-pull driving	0.33		0.45		0.48		0.53		0.67	
t _{sk(O)}	ChB-to-	ChA skew	Push-pull driving	0.28		0.24		0.23		0.23		0.22	ns
*SK(O)		l-to-Clock kew	Push-pull driving	1.51		1.58		1.46		1.56		1.48	113
	(Push-pull driving	60		80		120		120		120	
NA	Con	nmand	Open-drain driving	2		2		2		2		2	Mbps
Max data rate	С	lock	Push-pull driving	30		40		60		60		60	MHz
	D	ata	Push-pull driving	60		80		120		120		120	Mbps

SWITCHING CHARACTERISTICS

over operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1	1.5 V V	V _{CCB} = ± 0.15	1.8 V 5 V	V _{CCB} = ± 0.2	2.5 V 2 V	V _{CCB} = ± 0.3	3.3 V 3 V	UNIT
	(INPUT)	(OUTPUT)	CONDITIONS	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	CMDA	CMDB	Push-pull driving	4.4		11		7.4		4.4		3.8	
	CIVIDA	CIVIDB	Open-drain driving	143		544		596		605		669	
	CMDB	CMDA	Push-pull driving	3.8		7.6		5.5		4.2		3.7	
	CIVIDB	CIVIDA	Open-drain driving	137		434		444		414		372	ns
t _{PD}	CLKA	CLKB	Push-pull driving	4.1		12		8		4.8		3.8	IIS
	DATA	DATB	Duch pull driving	4.4		11		7		4.5		3.8	
	DATB	DATA	Push-pull driving	4.4		8		5.5		4.1		3.7	
	SEL	B-Port	Push-pull driving	7		18		13		10.5		9	
t _{rA}	A-port	rise time	Push-pull driving	1.4	0.75	2.2	0.74	2.2	1.06	2.6	0.7	2.8	
t _{rB}	B-port	rise time	Push-pull driving	6.3	1.91	7.7	1.34	6.1	0.95	4.2	0.83	3.2	ns
t _{rB}	CLKA	CLKB	Push-pull driving	5.2	1.67	6.4	1.27	4.9	0.9	3.2	0.76	2.6	
t _{fA}	A-port	fall time	Push-pull driving	1.1	0.58	1.9	0.58	2	0.61	1.9	0.57	1.9	
t _{fB}	B-port	fall time	Push-pull driving	3.6	1.04	5.4	0.87	4.3	0.66	3.4	0.57	3	ns
t _{fB}	CLKA	CLKB	Push-pull driving	3.1	0.92	4.2	0.79	3.2	0.56	2.2	0.49	1.9	
	ChA-to-	ChB skew	Push-pull driving	0.41		0.43		0.39		0.59		0.68	
t	ChB-to-	ChA skew	Push-pull driving	0.41		0.24		0.2		0.19		0.18	ns
t _{sk(O)}		el-to-Clock kew	Push-pull driving	2.11		1.47		1.3		1.25		1.21	113
	0		Push-pull driving	60		80		120		120		120	
	Con	nmand	Open-drain driving	2		2		2		2		2	Mbps
Max data rate	С	lock	Push-pull driving	30		40		60		60		60	MHz
	D	ata	Push-pull driving	60		80		120		120		120	Mbps



SWITCHING CHARACTERISTICS

over operating free-air temperature range, V_{CCA} = 3.3 V \pm 0.3 V (unless otherwise noted)

PARAMETER	FROM	TO	TEST	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = ± 0.15		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3	3.3 V 3 V	UNIT
	(INPUT)	(OUTPUT)	CONDITIONS	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	CMDA	CMDD	Push-pull driving	4.4		11		7		4.1		3.3	
	CMDA	CMDB	Open-drain driving	116		432		477		506		533	
	CMDB	CMDA	Push-pull driving	4.2		7.5		5.4		3.8		3	
	CIVIDB	CIVIDA	Open-drain driving	112		349		363		347		324	no
t _{PD}	CLKA	CLKB	Push-pull driving	4.1		12		7.8		4.4		3.5	ns
	DATA	DATB	Push-pull driving	4.3		11		6.8		4		3.8	
	DATB	DATA	Push-pull driving	7.9		7.8		5.4		3.4		3	
	SEL	B-Port	Push-pull driving	6.4		16		11.5		8.8		7.6	
t _{rA}	A-port	rise time	Push-pull driving	1.1	0.57	1.7	0.57	1.8	0.56	1.7	0.53	1.8	
t _{rB}	B-port	rise time	Push-pull driving	6.2	1.96	7.7	1.43	6.1	0.95	4.2	0.71	3.1	ns
t _{rB}	CLKA	CLKB	Push-pull driving	5.2	1.67	6.4	1.26	4.9	0.91	3.3	0.76	2.5	<u> </u>
t _{fA}	A-port	fall time	Push-pull driving	1	0.53	1.6	0.52	1.6	0.53	1.6	0.56	1.6	
t _{fB}	B-port	fall time	Push-pull driving	3.4	0.95	5.2	0.8	4.1	0.63	3.2	0.58	2.9	ns
t_{fB}	CLKA	CLKB	Push-pull driving	3.1	0.92	4.1	0.79	3.2	0.56	2.2	0.49	1.9	
	ChA-to-	ChB skew	Push-pull driving	0.39		0.36		0.39		0.57		0.65	
t _{sk(O)}	ChB-to-	ChA skew	Push-pull driving	0.45		0.3		0.19		0.19		0.18	ns
*sk(O)		el-to-Clock kew	Push-pull driving	1.7		1.61		1.34		1.22		1.14	
	0	d	Push-pull driving	60		80		120		120		120	N 41
Marrialata wata	Con	nmand	Open-drain driving	2		2		2		2		2	Mbps
Max data rate	С	lock	Push-pull driving	30		40		60		60		60	MHz
	С	ata	Push-pull driving	60		80		120		120		120	Mbps

OPERATING CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

						V_{CCA}			
				1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
		PARAMETER	TEST CONDITIONS			V _{CCB}	•	•	UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
				TYP	TYP	TYP	TYP	TYP	
	_	A-port input, B-port output		14.5	12.9	12.1	13.4	15	
Data	C _{pdA}	B-port input, A-port output	$C_L = 0$, $f = 10$ MHz,	20.7	20.7	21	22	23.2	
and		A-port input, B-port output	$t_r = t_r = 1 \text{ ns},$ OE = outputs enabled	23.2	23.4	23.6	24.5	25.5	pF
CMD	C_{pdB}	B-port input, A-port output	·	14.1	12.2	11.5	12.9	14.4	
		A-port input, B-port output	OE = outputs disabled	0.1	0.1	0.1	0.1	0.1	
	C_{pdA}	A-port input, B-port output	$C_L = 0$, $f = 10 \text{ MHz}$,	0.4	0.4	0.4	0.5	0.7	
Clock	C_{pdB}	B-port input, A-port output	$t_r = t_r = 1 \text{ ns},$ OE = outputs enabled	14	13.9	13.8	13.8	13.7	pF

POWER-UP CONSIDERATIONS

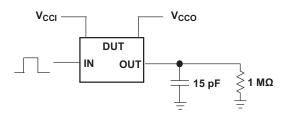
The following power-up sequence for this TXS02612 SDIO port expander with voltage-level translator should be followed to ensure proper operation and to avoid any unnecessary excessive supply current, bus contention, oscillations, or other anomalies caused by improperly biased device pins. The following power-up sequence should be used to safe-guard against these problems:

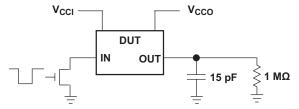
- 1. Connect the ground pin of the device first before any power-supply voltage is applied.
- 2. Connect and power up V_{CCA}, which internally powers up the SEL control logic of the TXS02612.
- 3. Depending on the port to be chosen, the SEL pin can be high or low. If SEL high is needed (i.e., A port to B_1 port), ramp the SEL pin with the V_{CCA} power supply. Otherwise, keep SEL Low.
- 4. Apply V_{CCB0} and V_{CCB1} only after the V_{CCA} power supply is applied.

 V_{CCA}



PARAMETER MEASUREMENT INFORMATION

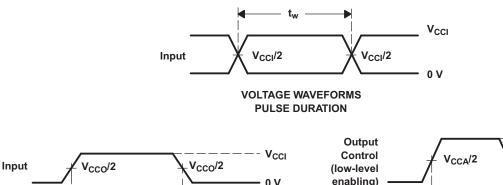


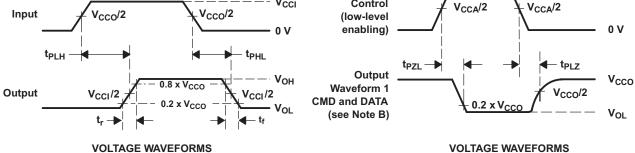


DATA RATE, PULSE DURATION, PROPAGATION DELAY, ENABLE/DISABLE
OUTPUT RISE AND FALL TIME MEASUREMENT USING
A PUSH-PULL DRIVER

DATA RATE, PULSE DURATION, PROPAGATION DELAY,
OUTPUT RISE AND FALL TIME MEASUREMENT USING
AN OPEN-DRAIN DRIVER

ENABLE AND DISABLE TIMES





NOTES:

- TES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is lowexcept when disabled by the output control. Waveform2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR 10 MHz, Z $_{\rm O}=50\Omega$, dv/dt \geq 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{HZ} are the same as t_{lis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{PZL} .
 - G. t_{PLH} and t_{HL} are the same as t_d.
 - H. V_{CCI} is the V_{CC} associated with the input port.
 - I. V_{CCO} is the V_{CC} associated with the output port.

PROPAGATION DELAY TIMES

J. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

www.ti.com 23-May-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TXS02612RTWR	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YJ612
TXS02612RTWR.B	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YJ612
TXS02612RTWRG4.B	Active	Production	WQFN (RTW) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YJ612

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS02612RTWR	WQFN	RTW	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2



PACKAGE MATERIALS INFORMATION

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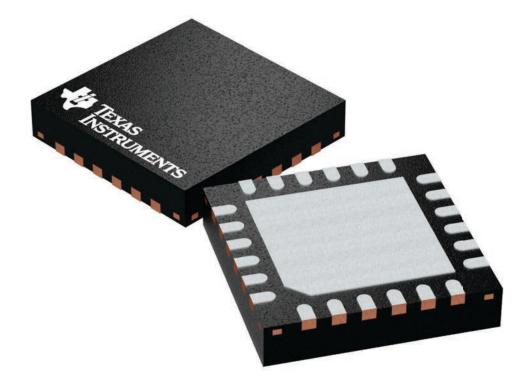
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS02612RTWR	WQFN	RTW	24	3000	356.0	356.0	35.0

4 x 4, 0.5 mm pitch

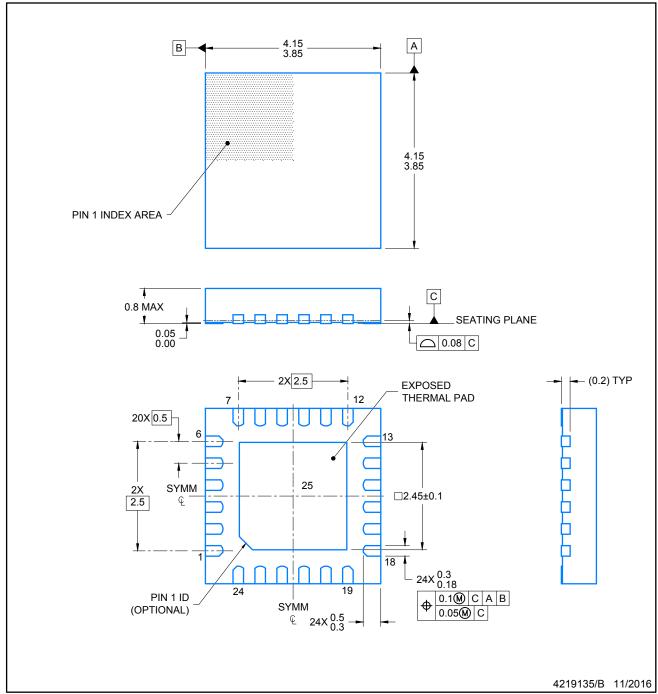
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK-NO LEAD

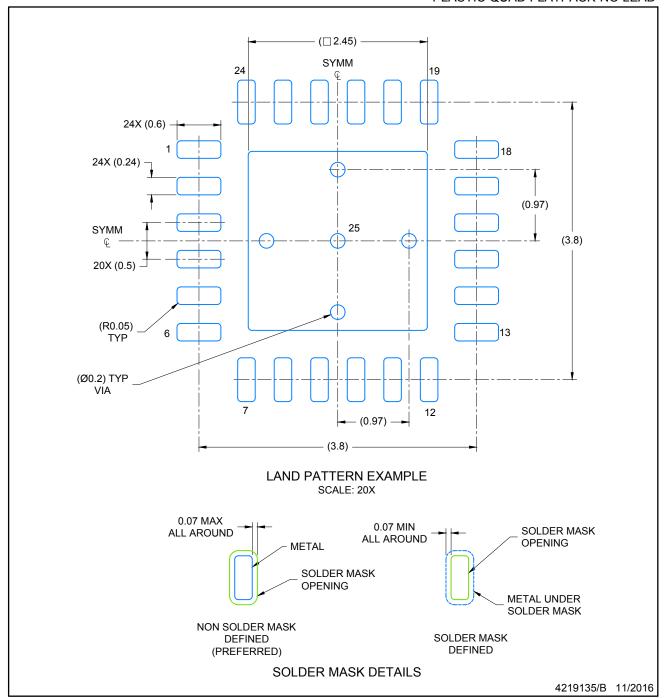


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



PLASTIC QUAD FLATPACK-NO LEAD

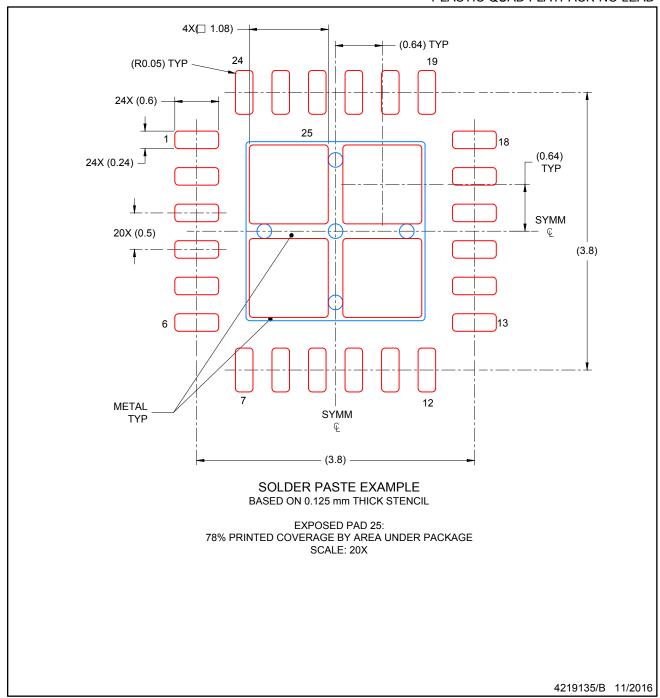


NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK-NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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